| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|---|---|---|---|---|---|---|
| S1 | 17045 | (tft or thin near film near transistor or amorphous near2 silicon or polycrystalline near2 silicon or poly near2 silicon or polysilicon or poly near2 si) and pixel near electrode | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 08:48 |
| S6 | 428 | (tft or thin near film near transistor or amorphous near2 silicon or polycrystalline near2 silicon or poly near2 silicon or polysilicon or poly near2 si) and (pixel near electrode) near8 (substrate) and (flat near panel near2 display) and (source or drain or channel or polycrystalline near silicon or polysilicon or polycrystalline near si or amorphous near silicon or a-si) near8 substrate | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 13:04 |
| S17 | 208 | pixel near electrode near3 (directly or on or upon or over) near substrate | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 08:37 |
| S29 | 86 | (display) and (tft or thin adj film adj electrode) and (gate adj oxide or gate adj insulating or gate adj insulator) near5 (upon or on or top or over or above) near5 (ito or transparent adj electrode or pixel adj electrode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 09:49 |
| S30 | 259 | pixel near electrode near3 (directly or on or upon or over) near substrate | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 08:37 |
| S31 | 108 | (display) and (tft or thin adj film adj electrode) and (gate adj oxide or gate adj insulating or gate adj insulator) near5 (upon or on or top or over or above) near5 (ito or transparent adj electrode or pixel adj electrode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 09:50 |
| S32 | 14 | (US-20020053668-$ or US-20010043292-$).did. or (US-5815223-$ or US-5926238-$ or US-5938942-$ or US-6087730-$ or US-6104040-$ or US-6190936-$ or US-6252247-$ or US-6275061-$ or US-6346978-$ or US-6559477-$ or US-6580226-$ or US-6576925-$).did. | US-PGPUB; USPAT | OR | ON | 2005/06/06 11:14 |
| S33 | 4 | "6480577".pn. "5010027".pn. "5897328".pn. "6111619".pn. | US-PGPUB; USPAT | OR | ON | 2005/06/06 11:40 |
| S34 | 3 | (pixel adj electrode or display adj electrode) near10 (buried adj oxide or buried adj insulator) | US-PGPUB; USPAT | OR | ON | 2005/06/06 11:42 |
| S35 | 10086 | (pixel adj electrode or display adj electrode) near10 (soi or substrate) | US-PGPUB; USPAT | OR | ON | 2005/06/06 11:43 |
| S36 | 13 | (pixel adj electrode or display adj electrode) near10 (soi) | US-PGPUB; USPAT | OR | ON | 2005/06/06 11:44 |
| S37 | 1414 | (tft or thin adj film adj transistor) same (gate or source or drain) near5 (pixel adj electrode) near4 layer | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 13:07 |
| S38 | 256 | (tft or thin adj film adj transistor) same (top adj gate) same (pixel adj electrode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 14:30 |
| S39 | 6 | ("4514253" | "4654117" | "5627103" | "5686326" | "5714790" | "5733804").PN. | US-PGPUB; USPAT; USOCR | OR | ON | 2005/06/06 14:20 |

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| S41 | 152 | (tft or thin adj film adj transistor) same (bottom adj gate) same (pixel adj electrode) not S38 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 15:29 |
| S42 | 438 | (tft or thin adj film adj transistor) same (gate) adj (insulator or oxide or insulating) near5 (pixel adj electrode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 15:29 |
| S43 | 82 | (tft or thin adj film adj transistor) same (gate) adj (insulator or oxide or insulating) near5 (over or above or top or upon or below or lower or under or underneath or overlying or underlying or beneath or covering) near5 (pixel adj electrode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/06 15:30 |
| S44 | 3813 | (tft or thin near film near transistor) and (pixel or display) near electrode and (oel or oled or electrolumines$6 or electro-lumines$6) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 08:50 |
| S45 | 2422 | (tft or thin adj film adj transistor) and ((pixel or display) near electrode) near8 (gate or source or drain) and (oel or oled or electrolumines$6 or electro-lumines$6) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 08:51 |
| S46 | 122 | (tft or thin adj film adj transistor) and ((pixel or display) near electrode) near8 (gate adj oxide or gate adj insulat$3) and (oel or oled or electrolumines$6 or electro-lumines$6) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 10:02 |
| S47 | 2 | ("20030107326" \| "20030117059").PN. | US-PGPUB; USPAT; USOCR | OR | ON | 2005/06/08 09:38 |
| S48 | 1675 | (tft or thin adj film adj transistor) and ((pixel or display) near electrode) near8 (substrate or buried adj oxide or buried adj insulat$3) and (oel or oled or electrolumines$6 or electro-lumines$6) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 10:02 |
| S49 | 314 | (tft or thin adj film adj transistor) and ((pixel or display) near electrode) near5 (substrate or buried adj oxide or buried adj insulat$3) and (oel or oled or electrolumines$6 or electro-lumines$6) near6 (anode or cathode or electrode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 10:56 |
| S50 | 196 | (tft or thin adj film adj transistor) and (substrate or buffer or buffered) near8 (cathode or anode or pixel adj electrode) near8 (gate or drain or source or semiconductor or active) and (oel or oled or electrolumines$6 or electro-lumines$6 or light near emitting or light near emissive) near3 (layer or stacked or disposed or upon or directly or over or adjacent) near3 (anode or cathode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 11:22 |
| S51 | 226 | (tft or thin adj film adj transistor) and (oel or oled or organic near light near (emitting or emissive) or electrolumines$5 or electro-lumines$5) and (cathode or anode or pixel near electrode or display near electrode) near4 (before or earlier or prior or after or later) near6 (active or gate or source or drain or tft) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 11:40 |
| S52 | 2 | ("5706064" \| "5986724").PN. | US-PGPUB; USPAT; USOCR | OR | ON | 2005/06/08 11:33 |
| S53 | 99 | (tft or thin adj film adj transistor) and (oel or oled or organic near light near (emitting or emissive) or electrolumines$5 or electro-lumines$5) and (cathode or anode or pixel near electrode or display near electrode) near4 (simultan$6 or concurrent$5 or "same" near time or together or "same" near layer) near6 (active or gate or source or drain or tft) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 11:41 |

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| S55 | 19 | (US-20010043292-$ or US-20020053668-$ or US-20040169991-$).did. or (US-5671027-$ or US-5815223-$ or US-5926238-$ or US-5938942-$ or US-6087730-$ or US-6104040-$ or US-6190936-$ or US-6252247-$ or US-6275061-$ or US-6346978-$ or US-6372558-$ or US-6440784-$ or US-6559477-$ or US-6576925-$ or US-6580226-$ or US-6855960-$).did. | US-PGPUB; USPAT | OR | ON | 2005/06/08 16:48 |
| S56 | 250 | (tft or thin adj film adj transistor) same (bottom adj gate) same (pixel adj electrode) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 14:17 |
| S57 | 873 | (tft or thin adj film adj transistor) and (oel or oled or electrolumines$5 or electro-lumines$5) near5 (lcd or liquid adj crystal) and (pixel near electrode or display near electrode or anode or cathode) near3 (gate or source or drain or substrate) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 14:19 |
| S58 | 661 | (tft or thin adj film adj transistor) and (oel or oled or electrolumines$5 or electro-lumines$5) near5 (lcd or liquid adj crystal) and (pixel near electrode or display near electrode or anode or cathode) near3 (gate or substrate) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 14:19 |
| S59 | 111 | (tft or thin adj film adj transistor) and (oel or oled or electrolumines$5 or electro-lumines$5) near5 (lcd or liquid adj crystal) and (pixel near electrode or display near electrode or anode or cathode) near3 (gate or substrate) near3 (directly or upon or over or above or below or "same" near level or "same" near layer or adjacent or touching or under or underneath) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/06/08 14:21 |